

TEA2206T

Active bridge rectifier controller

Rev. 1.1 — 14 April 2021

Product data sheet

1 General description

The TEA2206T is an active bridge rectifier controller for replacing the two low-side diodes in the traditional diode bridge with MOSFETs.

Using the TEA2206T with low-ohmic high-voltage external MOSFETs significantly improves the efficiency of the power converter as the typical rectifier-diode forward-conduction losses are reduced by 50 %. Efficiency can improve up to about 0.7 % at 90 V (AC) mains voltage.

The TEA2206T is fabricated in a silicon-on-insulator (SOI) process.

2 Features and benefits

2.1 Efficiency features

- · Forward conduction losses of the diode rectifier bridge are reduced
- Very low IC power consumption (2 mW)

2.2 Application features

- · Directly drives two rectifier MOSFETs
- Very low external part count
- Integrated X-capacitor discharge (2 mA)
- Self-supplying
- SO8 package

2.3 Control features

- Undervoltage lockout
- Drain-source overvoltage protection for all external power MOSFETs
- Gate pull-down currents at startup for all external power MOSFETs

3 Applications

The TEA2206T is intended for power supplies with a boost-type power-factor controller as a first stage. The second stage can be a resonant controller, a flyback controller, or any other controller topology. It can be used in all power supplies requiring high efficiency:

- Adapters
- · Power supplies for desktop PC and all-in-one PC
- · Power supplies for television
- · Power supplies for servers



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4 Ordering information

Table 1. Ordering information

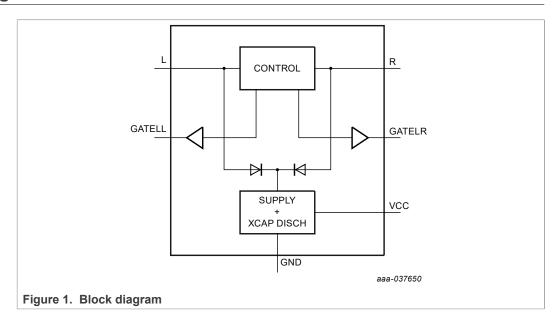
Type number	Package					
	Name	Description	Version			
TEA2206T/1	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1			

5 Marking

Table 2. Marking

Type number	Marking code
TEA2206T/1	TEA2206

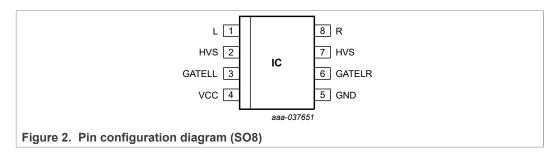
6 Block diagram



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7 Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

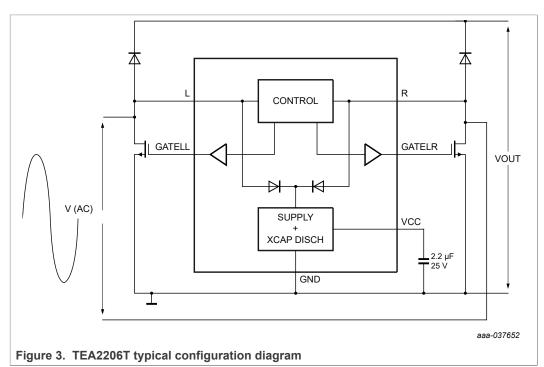
Symbol	Pin	Description
L	1	left input
HVS	2	high-voltage spacer; not to be connected
GATELL	3	gate driver left low side
VCC	4	supply voltage
GND	5	ground
GATELR	6	gate driver right low side
HVS	7	high-voltage spacer; not to be connected
R	8	Right input

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8 Functional description

8.1 Introduction

The TEA2206T is a controller IC for an active bridge rectifier consisting of two diodes and two MOSFETs. It can directly drive the two MOSFETs. Figure 1 shows a typical configuration. It is intended for applications followed by a boost type power factor circuit.



8.2 Operation

The control circuit of the TEA2206T senses the polarity of the mains voltage between pins L and R. Depending on the polarity, either GATELL or GATELR is switched on. The comparator in the control circuit, which compares the L and R voltages, has thresholds of 250 mV and −250 mV depending on the slope polarity. If the difference voltage between L and R is less than 250 mV both GATELL and GATELR are low.

The gate drivers are high-current rail-to-rail MOS output drivers. An on-chip supply circuit which draws current from either L or R generated the gate driver voltage. After a zero-crossing of the mains voltage, the supply capacitor C_{VCC} is charged to the regulation level V_{reg} . Then the discharge state is entered. The resulting power dissipation from the mains voltage is about 1 mW excluding gate charge losses of the external power MOSFETs. These gate charge losses typically add 1 mW of dissipation.

At start-up, the supply capacitor is first charged to the V_{start} voltage and enters the start-up state. After a next zero-crossing of the mains voltage, the supply capacitor is charged to V_{reg} in the charging state. When the voltage at the supply capacitor exceeds V_{dis} , the gate driver outputs are enabled. When all drivers are active, the MOSFETs take over the role of the diodes which, compared to a passive diode rectifier bridge, results in lower power loss.

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When the mains voltage is disconnected, the internal bias current in the discharge state discharges the supply capacitor. When the voltage at pin VCC drops to below $V_{\rm dis}$ the X-capacitor discharge state is entered, which draws 2 mA of current from pin L or pin R to discharge the X-capacitor. The waiting time $t_{\rm d}$ until X-capacitor discharge starts is:

$$t_d = C_{VCC} * (V_{reg} - V_{dis}) / 20 \ \mu A = 0.2E6 * C$$
 (1)

Using a typical value of 2.2 μ F for C_{VCC} yields about 0.45 s. While the L or R pin discharges the X-capacitor, the mains can be reconnected. In that case, the charge mode is entered again.

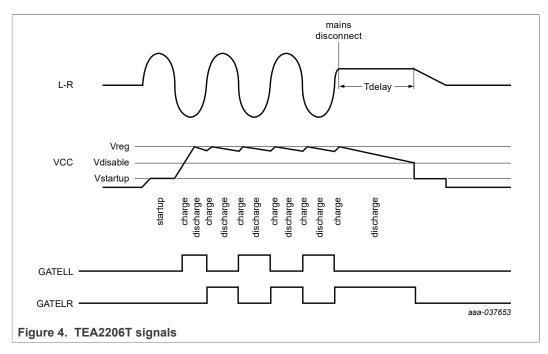


Table 4. TEA2206T states

States	Description	I (L) or I (R)	I (VCC)
start-up	supply capacitor kept stable at 4.8 V	2 mA	0
charge	supply capacitor is being charged with 2 mA from pin L or R	2 mA	-2 mA
discharge	internal bias currents and gate charge losses discharge the supply capacitor	1 μΑ	20 μΑ
x-capacitor discharge	supply capacitor and x-capacitor are being discharged by 2 mA	2 mA	-2 mA

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8.3 Protections

8.3.1 Gate pull-down

All gate driver outputs have a pull-down circuit. This circuit ensures that, if a driver supply voltage is below the undervoltage lockout level, the gate driver output is discharged to less than 2 V.

8.3.2 Power MOSFET drain-source protection

If the drain-source voltage of the external power MOSFET exceeds V_{VCC} – 2 V, all gate driver outputs are disabled. It avoids high dissipation and high current peaks in the power MOSFETs during start-up.

8.3.3 Minimum mains voltage

Only when the voltage at either node L or R exceeds 22 V, the charge state is entered.

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9 Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are measured with respect to ground (pin 7); positive currents flow into the chip. Voltage ratings are valid provided other ratings are not violated; current ratings are valid provided the other ratings are not violated.

Symbol	Parameter	Conditions	Min	Max	Unit
Voltages			1		
V _L	voltage on pin L	operating	-5	+440	V
		mains transient: maximum 10 minutes over lifetime	-5	+700	V
V _R	voltage on pin R	operating	-5	+440	V
		mains transient: maximum 10 minutes over lifetime	-5	+700	V
SR _{max}	maximum slew rate	pins L and R	-	50	V/ns
V _{VCC}	voltage on pin VCC		-0.4	14	V
V _{GATELL}	voltage on pin GATELL		-0.4	14	V
V _{GATELR}	voltage on pin GATELR		-0.4	14	V
General			<u>'</u>		
Tj	junction temperature		-40	+125	°C
T _{stg}	storage temperature		-55	+150	°C
Electrosta	atic discharge		<u>'</u>		
V _{ESD}	electrostatic discharge voltage	human body model (HBM)			
		pins L and R	-1000	+1000	V
		other pins	-2000	+2000	V
		charge device model (CDM)	-500	+500	V

10 Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	in free air	46	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air; 1-layer PCB	177	K/W
		in free air; 4-layer PCB; JEDEC test board [1]	126	K/W

^[1] Given thermal resistance values are based on simulation results.

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11 Characteristics

Table 7. Characteristics

 T_{amb} = 25 °C; all voltages are measured with respect to GND; currents are positive when flowing into the IC; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
High-volta	age supply (pins L and R)						
l _{on}	on-state current	charging state; X- capacitor discharge state; start- up state		1.5	2	2.75	mA
l _{off}	off-state current	discharge state		0.9	1.3	1.8	μΑ
V _{start}	start voltage	high-voltage start-up		9	-	-	V
Low-volta	ge supply (pin VCC)						
I _{dch}	discharge current	X-capacitor discharge		3	4	5.5	mA
I _{bias}	bias current	discharge state		15	20	30	μA
I _{ch}	charge current	charge state		1.5	2	2.75	mA
V _{UVLO}	undervoltage lockout voltage			3.6	4.2	4.9	V
V _{startup}	start-up voltage	start-up state		4.3	4.8	5.3	V
V _{dis}	disable voltage	high level		9.2	9.7	10.2	V
		hysteresis		1.1	1.5	1.8	V
V _{regd}	regulated output voltage			11.4	12	12.8	V
Gate drive	er output pins (GATELL, GATELR)					
I _{source}	source current	V _{VCC} = 12 V; V _{gate} = 6 V	[1]	125	200	400	mA
I _{sink}	sink current	V _{VCC} = 12 V; V _{gate} = 6 V	[1]	150	200	500	mA
I _{pd}	pull-down current	V _{VCC} = 2 V; V _{gate} = 2 V		100	200	250	μA
R _{on}	on-state resistance			11	15	20	Ω
R _{off}	off-state resistance			7	10	14	Ω
$V_{\text{prot}(G)}$	gate driver protection voltage	L-VCC; R-VCC		-3	-2.3	-1	V
Control c	ircuit (pins L and R)				'		
V _{th}	threshold voltage	peak detector threshold voltage		15	22	32	V
V_{offset}	offset voltage	Zero crossing comparator offset voltage		150	250	350	mV
t _d	delay time	dV/dt = 0.1 V/μs	[2]	1200	1500	2500	ns
		dV/dt = 10 V/μs	[2]	550	700	1200	ns

Covered by correlating measurement. Guaranteed by design and validation.

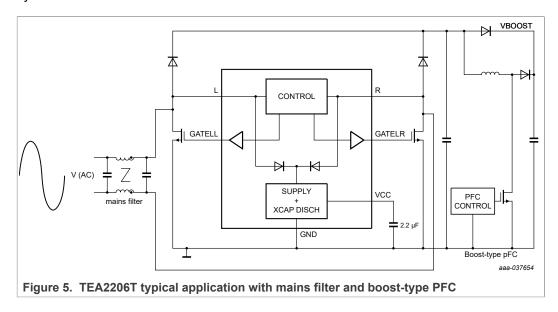
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12 Application information

A switched mode power supply with the TEA2206T typically consists of a mains filter in front of the TEA2206T followed by a boost-type power-factor controller. A resonant controller, flyback controller, or any other topology can follow this boost-type PFC.

Special attention must be paid to the connection of the L and R pins of the TEA2206T. Mains transients or surges must be limited to voltages below 700 V.

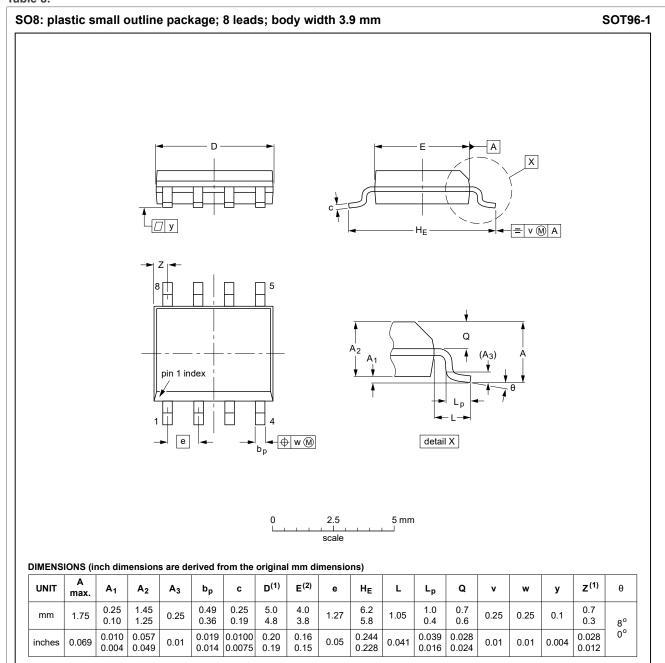
Typical value for the supply capacitor is 1 μ F to 2.2 μ F. Supply capacitors with higher values increase the delay time (t_d) for the X-capacitor discharge. They may also increase the dissipation because the supply capacitor C_{VCC} may not be charged every half-mains cycle.



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13 Package outline

Table 8.



Notes

- 1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT96-1	076E03	MS-012				99-12-27 03-02-18

Figure 6. Package outline SOT96-1 (SO8)

TEA2206

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14 Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
TEA2206T v.1.1	20210414	Product data sheet	-	TEA2206T v.1			
Modifications:	Characteristics "	<u>Characteristics</u> "Characteristics" has been updated.					
TEA2206T v.1	20201202	Product data sheet	-	-			

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15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.	
Product [short] data sheet	Production	This document contains the product specification.	

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